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Building a graphene nanoribbon device

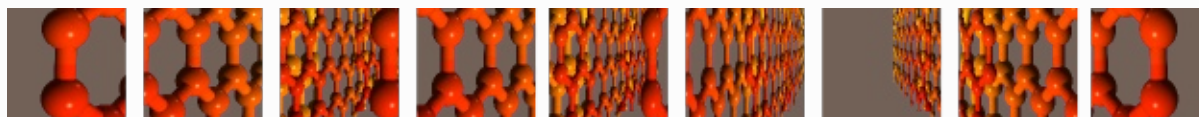
Building a graphene nanoribbon device

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You will here learn how to build the device configuration used in the tutorial [Transport in a graphene nanoribbon with a distortion](#).

The simplest way to build a device is to first build the desired scattering region as a bulk, including any defects and other deviations from perfect periodicity, and then use the *Device from Bulk* plugin to construct and attach the electrodes. Geometry optimization should also be considered; this can be done before and/or after the device is “assembled”.



Bulk central region

First step is to build a perfect (defect free) graphene nanoribbon. Open the  Builder and use the **Nanoribbon** plugin to create a rather narrow ribbon with chiral indices (2,2), corresponding to a zigzag nanoribbon, 8 carbon atoms wide. Then use the Bulk Tools ► Repeat tool to repeat the nanoribbon unit cell 12 times along the C direction.

Tip

Use the keyboard shortcut Ctrl+R to center the 3D view after applying the repeat operation.

Create the structure in **Builder**

Stash
Add
Copy
Delete

New Configuration
From Files...
From Database...
From Plugin
From Clipboard

Nanoribbon
Nanosheet
Crystallography Open Database
Magnetic Tunnel Junction (FeMgO-style)
Nanotube
Crystal Builder

Bulk Tools
▼ Repeat
Set the repetition to choose the number of times the configuration should be repeated along the A, B, and C-axes.
A = 1 B = 1 C = 12
To perform the repeat operation, press the **Apply** button.

Nanoribbon
Chemical Properties
Carbon Carbon
Bond length 1.42086 Å
☒ Passivate dangling bonds with hydrogen
Geometry
☒ Align unit cell vector C with chiral vector n = 2 m = 2
☐ Zigzag edge
☐ Armchair edge 4 atoms wide
Preview Build

Builder
File Edit Selection View Windows Help
Bulk
Stash
Add
Copy
Delete
(2,2) Graph...

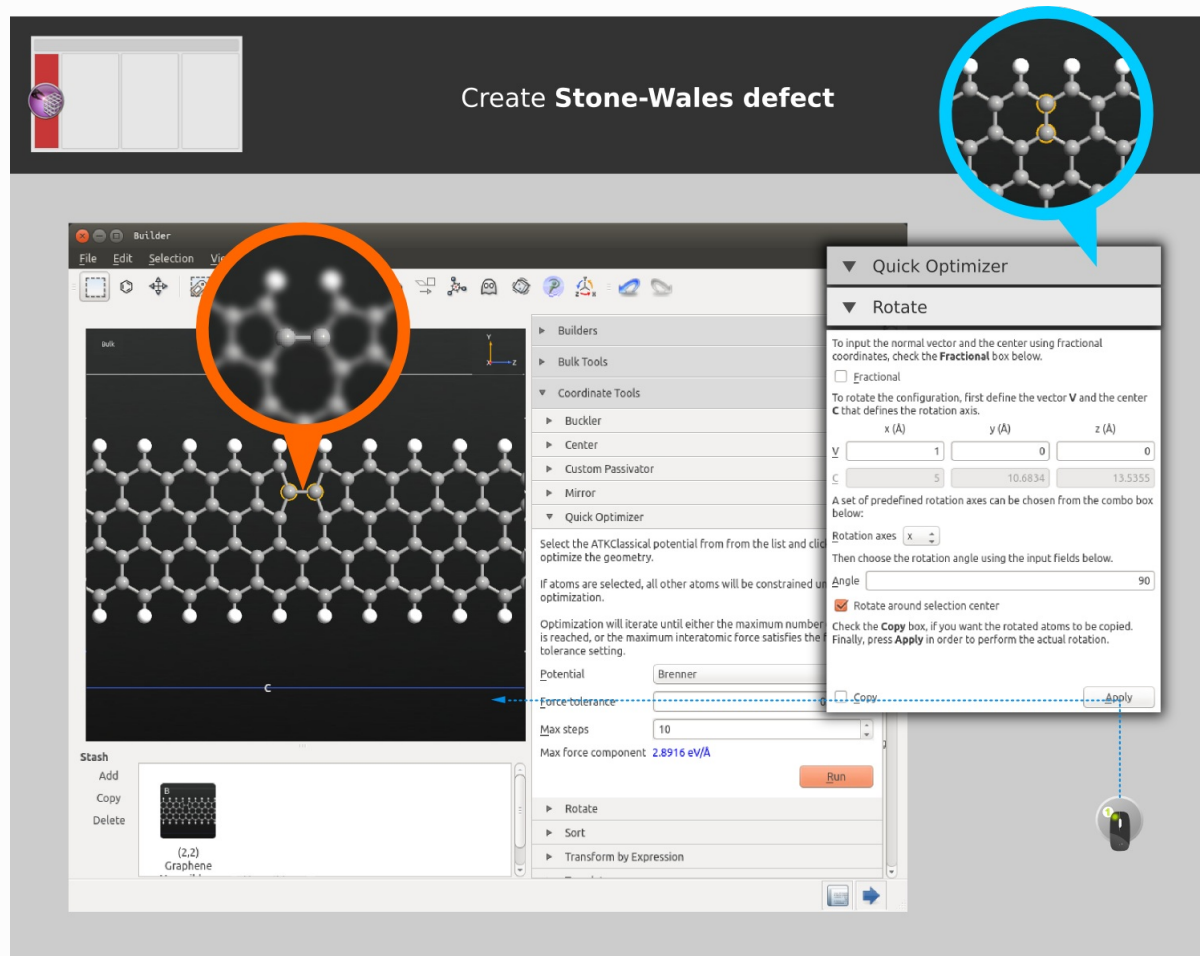
Builders
Bulk Tools
Crystal Symmetry Info
Fit Cell
Merge Cells
Repeat
Stretch Cell
Supercell
Swap Axes
Wrap
Brillouin Zone Viewer...
Lattice Parameters...
Coordinate Tools
Device Tools
Graphics
Miscellaneous

Defect in the scattering region

Let us now create a Stone–Wales defect in the middle of the nanoribbon – in what will become the scattering region in the nanoribbon device.

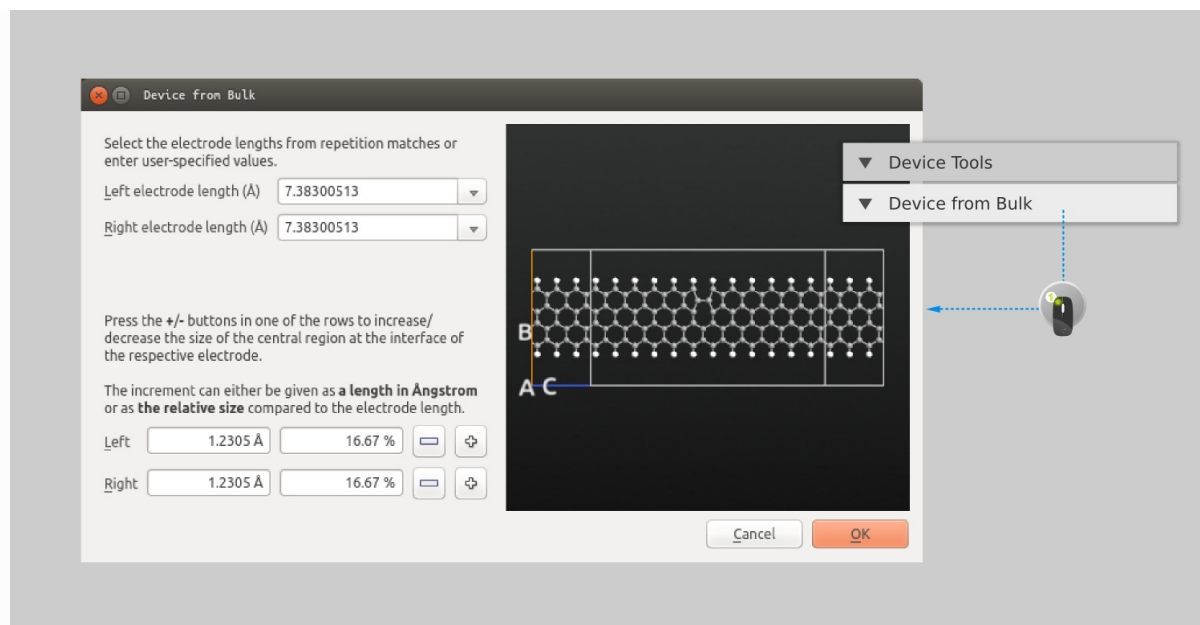
Select the two atoms indicated in the figure below (they both have a z-coordinate about 13.5 Å) by holding down Ctrl while clicking them. Then use the Coordinate Tools ► Rotate tool to rotate them 90

degrees around the X axis. Keep the *Rotate around selection center* box checked while applying the rotation.



Device from Bulk

Next step is to build the actual device. Select the nanoribbon Stash item, and navigate to the Device Tools ► Device from Bulk plugin. The purpose of this plugin is to attach left and right electrodes to the defected central region created above.



The plugin automatically detects the periodicity of the region closest to the edges of the central region, and suggests valid electrodes. In order for this to work well, there should be at least one full period plus one additional layer of the electrode present in the central region. The suggested 7.38 Å electrodes is a reasonable choice for this system (3 periods of the nanoribbon cell).

❗ Important

You should in general be careful not to make the central region too short along the C direction: It must be long enough to accommodate any defects you introduce as well as a perfectly periodic structure in both ends, where the central region meets the electrodes.

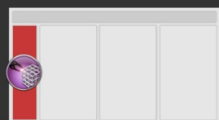
The electrodes should also not be too short: They must be able to include all relevant Hamiltonian matrix elements with the central region. A rough estimate is 7–8 Å in many systems.

Both points above relate to the concepts of *electrode extensions* and *scattering region*, which you can learn more about in the tutorials [Transport calculations with ATK](#) and [Transport in a graphene nanoribbon with a distortion](#).

Optimizing the geometry

The perfect nanoribbon central region was created without any geometry optimization. Although the C–C and C–H bond lengths are most likely very close to optimum far from the Stone–Wales defect, the local geometry around the defect certainly needs force minimization.

The Builder offers the very convenient **Quick Optimizer** plugin, which uses fast pair-potential calculations implemented in the ATK-Classical calculator engine. Choose the *Brenner* potential and click **Run** to execute 10 geometry optimization steps.



Optimize the structure

The screenshot shows the QuantumWise Builder interface. The main window displays a 3D model of a device structure, specifically a (2,2) Graphene nanoribbon. A red circle highlights a specific region of the structure. On the right, the 'Quick Optimizer' panel is open, showing settings for the optimization process. The 'Potential' is set to 'Brenner', 'Force tolerance' is 0.05 eV/Å, and 'Max steps' is 10. The 'Max force component' is 2.8916 eV/Å. A red 'Run' button is visible. A mouse cursor is shown clicking the 'Run' button. Below the main window, a 'Stash' panel shows two device configurations: '(2,2) Graphene' and 'Device: (2,2) Graphene'.

Note

Although it may not be obvious to the naked eye, the electrode extensions in both ends of the central region are automatically **constrained** during a device geometry optimization. This retains their exact geometric correspondence to the neighboring electrode.

10 optimizer steps are not enough to fully minimize the forces. Increase the maximum number of steps to 100 and run one more geometry optimization to reach full convergence.

Tip

The Quick Optimizer can also be used to pre-minimize the forces in a configuration prior to performing a relaxation with DFT, which is computationally more heavy. However, beware that high-quality classical potentials are not available for all possible combinations of elements.

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